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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

| | |
|----------------------------|---|
| Product Status | Active |
| Core Processor | RL78 |
| Core Size | 16-Bit |
| Speed | 32MHz |
| Connectivity | CSI, I ² C, IrDA, LINbus, UART/USART |
| Peripherals | LVD, POR, PWM, WDT |
| Number of I/O | 44 |
| Program Memory Size | 64KB (64K x 8) |
| Program Memory Type | FLASH |
| EEPROM Size | 4K x 8 |
| RAM Size | 5.5K x 8 |
| Voltage - Supply (Vcc/Vdd) | 1.6V ~ 5.5V |
| Data Converters | A/D 17x10b; D/A 1x8b |
| Oscillator Type | Internal |
| Operating Temperature | -40°C ~ 85°C (TA) |
| Mounting Type | Surface Mount |
| Package / Case | 48-LQFP |
| Supplier Device Package | 48-LQFP (7x7) |
| Purchase URL | https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f11bgeafb-50 |

1.6 Outline of Functions

Caution This outline describes the functions at the time when Peripheral I/O redirection register 0, 1 (PIOR0, 1) are set to 00H.

(1/2)

| Item | | 24-pin | 32-pin | 36-pin | 48-pin | 64-pin |
|------------------------------------|--|--|--|--|---|--|
| | | R5F11B7x (x = C, E) | R5F11BBx (x = C, E) | R5F11BCx (x = C, E) | R5F11BGx (x = C, E) | R5F11BLx (x = C, E) |
| Code flash memory (KB) | | 32, 64 | 32, 64 | 32, 64 | 32, 64 | 32, 64 |
| Data flash memory (KB) | | 4 | 4 | 4 | 4 | 4 |
| RAM (KB) | | 5.5 Note | 5.5 Note | 5.5 Note | 5.5 Note | 5.5 Note |
| Address space | | 1 MB | | | | |
| Main system clock | High-speed system clock | X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (high-speed main) mode: 1 to 20 MHz (V _{DD} = 2.7 to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz (V _{DD} = 2.4 to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz (V _{DD} = 1.8 to 2.7 V), LV (low-voltage main) mode: 1 to 4 MHz (V _{DD} = 1.6 to 1.8 V) | | | | |
| | High-speed on-chip oscillator clock (f _{IH}) | HS (high-speed main) mode: 1 to 32 MHz (V _{DD} = 2.7 to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz (V _{DD} = 2.4 to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz (V _{DD} = 1.8 to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz (V _{DD} = 1.6 to 5.5 V) | | | | |
| Subsystem clock | | — | | | XT1 (crystal) oscillation, external subsystem clock input (EXCLKS) 32.768 kHz | |
| Low-speed on-chip oscillator clock | | 15 kHz (TYP.): V _{DD} = 1.6 to 5.5 V | | | | |
| General-purpose register | | 8 bits × 32 registers (8 bits × 8 registers × 4 banks) | | | | |
| Minimum instruction execution time | | 0.03125 μs (High-speed on-chip oscillator clock: f _{IH} = 32 MHz operation) | | | | |
| | | 0.05 μs (High-speed system clock: f _{MX} = 20 MHz operation) | | | | |
| | | — | | | 30.5 μs (Subsystem clock: f _{SUB} = 32.768 kHz operation) | |
| Instruction set | | <ul style="list-style-type: none">• Data transfer (8/16 bits)• Adder and subtractor/logical operation (8/16 bits)• Multiplication (8 bits × 8 bits, 16 bits × 16 bits), Division (16 bits ÷ 16 bits, 32 bits ÷ 32 bits)• Multiplication and Accumulation (16 bits × 16 bits + 32 bits)• Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc. | | | | |
| I/O port | Total | 20 | 28 | 31 | 44 | 58 |
| | CMOS I/O | 17 (N-ch O.D. output [V _{DD} withstand voltage]: 10) | 25 (N-ch O.D. output [V _{DD} withstand voltage]: 12) | 24 (N-ch O.D. output [V _{DD} withstand voltage]: 10) | 34 (N-ch O.D. output [V _{DD} withstand voltage]: 12) | 48 (N-ch O.D. output [V _{DD} withstand voltage]: 12) |
| | CMOS input | 3 | 3 | 5 | 5 | 5 |
| | CMOS output | — | — | — | 1 | 1 |
| | N-ch open-drain I/O (6 V tolerance) | — | — | 2 | 4 | 4 |
| | Timer | | 9 channels (TAU: 4 channels, Timer RJ: 1 channel, Timer RD: 2 channels (with PWMOPA), Timer RX: 1 channel, Timer RG: 1 channel) | | | |
| | Watchdog timer | 1 channel | | | | |
| | Real-time clock (RTC) | 1 channel | | | | |
| | 12-bit interval timer | 1 channel | | | | |
| | Timer output | Timer outputs: 13 channels PWM outputs: 8 channels | Timer outputs: 16 channels PWM outputs: 9 channels | | | |
| | RTC output | — | | | 1 • 1 Hz (subsystem clock: f _{SUB} = 32.768 kHz) | |

Note This is about 4.5 KB when the self-programming function and data flash function are used (For details, see **CHAPTER 3** in the RL78/G1F User's Manual).

2.1 Absolute Maximum Ratings

Absolute Maximum Ratings

(1/2)

| Parameter | Symbols | Conditions | Ratings | Unit |
|------------------------|---------------------|---|---|------|
| Supply voltage | V _{DD} | | -0.5 to +6.5 | V |
| | EV _{DD0} | | -0.5 to +6.5 | V |
| REGC pin input voltage | V _I REGC | REGC | -0.3 to +2.8 and -0.3 to V _{DD} +0.3 Note 1 | V |
| Input voltage | V _{I1} | P00 to P06, P10 to P17, P30, P31, P40 to P43, P50 to P55, P70 to P77, P120, P140, P141, P146, P147 | -0.3 to EV _{DD0} +0.3 and -0.3 to V _{DD} +0.3 Note 2 | V |
| | V _{I2} | P60 to P63 (N-ch open-drain) | -0.3 to +6.5 | V |
| | V _{I3} | P20 to P27, P121 to P124, P137, EXCLK, EXCLKS, RESET | -0.3 to V _{DD} +0.3 Note 2 | V |
| Output voltage | V _{O1} | P00 to P06, P10 to P17, P30, P31, P40 to P43, P50 to P55, P60 to P63, P70 to P77, P120, P130, P140, P141, P146, P147 | -0.3 to EV _{DD0} +0.3 and -0.3 to V _{DD} +0.3 Note 2 | V |
| | V _{O2} | P20 to P27 | -0.3 to V _{DD} +0.3 Note 2 | V |
| Analog input voltage | V _{AI1} | ANI16 to ANI24 | -0.3 to EV _{DD0} +0.3 and -0.3 to AV _{REF} (+) +0.3 Notes 2, 3 | V |
| | V _{AI2} | ANI0 to ANI7 | -0.3 to V _{DD} +0.3 and -0.3 to AV _{REF} (+) +0.3 Notes 2, 3 | V |

Note 1. Connect the REGC pin to V_{SS} via a capacitor (0.47 to 1 μF). This value regulates the absolute maximum rating of the REGC pin. Do not use this pin with voltage applied to it.

Note 2. Must be 6.5 V or lower.

Note 3. Do not exceed AV_{REF} (+) + 0.3 V in case of A/D conversion target pin.

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

Remark 1. Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

Remark 2. AV_{REF} (+): + side reference voltage of the A/D converter.

Remark 3. V_{SS}: Reference voltage

2.2 Oscillator Characteristics

2.2.1 X1, XT1 characteristics

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = VDD ≤ 5.5 V, VSS = 0 V)

| Resonator | Resonator | Conditions | MIN. | TYP. | MAX. | Unit |
|---|---|---------------------|------|--------|------|------|
| X1 clock oscillation frequency (fx) ^{Note} | Ceramic resonator/ crystal resonator | 2.7 V ≤ VDD ≤ 5.5 V | 1.0 | | 20.0 | MHz |
| | | 2.4 V ≤ VDD < 2.7 V | 1.0 | | 16.0 | |
| | | 1.8 V ≤ VDD < 2.4 V | 1.0 | | 8.0 | |
| | | 1.6 V ≤ VDD < 1.8 V | 1.0 | | 4.0 | |
| XT1 clock oscillation frequency (fxT) ^{Note} | Crystal resonator | | 32 | 32.768 | 35 | kHz |

Note Indicates only permissible oscillator frequency ranges. Refer to **AC Characteristics** for instruction execution time.
Request evaluation by the manufacturer of the oscillator circuit mounted on a board to check the oscillator characteristics.

Caution Since the CPU is started by the high-speed on-chip oscillator clock after a reset release, check the X1 clock oscillation stabilization time using the oscillation stabilization time counter status register (OSTC) by the user. Determine the oscillation stabilization time of the OSTC register and the oscillation stabilization time select register (OSTS) after sufficiently evaluating the oscillation stabilization time with the resonator to be used.

Remark When using the X1 oscillator and XT1 oscillator, refer to **5.4 System Clock Oscillator** in the RL78/G1F User's Manual.

2.2.2 On-chip oscillator characteristics

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = VDD ≤ 5.5 V, VSS = 0 V)

| Oscillators | Parameters | Conditions | MIN. | TYP. | MAX. | Unit |
|---|-----------------|---------------------|---------------------|------|------|------|
| High-speed on-chip oscillator clock frequency Notes 1, 2 | f _{IH} | 2.7 V ≤ VDD ≤ 5.5 V | 1 | | 32 | MHz |
| | | 2.4 V ≤ VDD < 2.7 V | 1 | | 16 | MHz |
| | | 1.8 V ≤ VDD < 2.4 V | 1 | | 8 | MHz |
| | | 1.6 V ≤ VDD < 1.8 V | 1 | | 4 | MHz |
| High-speed on-chip oscillator clock frequency accuracy | | TA = -20 to +85°C | 1.8 V ≤ VDD ≤ 5.5 V | -1 | 1 | % |
| | | | 1.6 V ≤ VDD < 1.8 V | -5 | 5 | % |
| | | TA = -40 to -20°C | 1.8 V ≤ VDD ≤ 5.5 V | -1.5 | 1.5 | % |
| | | | 1.6 V ≤ VDD < 1.8 V | -5.5 | 5.5 | % |
| Low-speed on-chip oscillator clock frequency | f _{IL} | | | 15 | | kHz |
| Low-speed on-chip oscillator clock frequency accuracy | | | -15 | | +15 | % |

Note 1. High-speed on-chip oscillator frequency is selected with bits 0 to 4 of the option byte (000C2H) and bits 0 to 2 of the HOCODIV register.

Note 2. This only indicates the oscillator characteristics. Refer to **AC Characteristics** for instruction execution time.

(4) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input)**(TA = -40 to +85°C, 1.6 V ≤ EVDD0 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = 0 V)**

| Parameter | Symbol | Conditions | | HS (high-speed main) mode | | LS (low-speed main) mode | | LV (low-voltage main) mode | | Unit |
|---|------------|---------------------------------|-----------------------|---------------------------|--------------|--------------------------|--------------|----------------------------|--------------|------|
| | | | | MIN. | MAX. | MIN. | MAX. | MIN. | MAX. | |
| SCKp cycle time <small>Note 5</small> | tkCY2 | 4.0 V ≤ EVDD0 ≤ 5.5 V | 20 MHz < fMCK | 8/fMCK | | — | | — | | ns |
| | | | fMCK ≤ 20 MHz | 6/fMCK | | 6/fMCK | | 6/fMCK | | ns |
| | | 2.7 V ≤ EVDD0 ≤ 5.5 V | 16 MHz < fMCK | 8/fMCK | | — | | — | | ns |
| | | | fMCK ≤ 16 MHz | 6/fMCK | | 6/fMCK | | 6/fMCK | | ns |
| | | 2.4 V ≤ EVDD0 ≤ 5.5 V | | 6/fMCK and 500 | | 6/fMCK and 500 | | 6/fMCK and 500 | | ns |
| | | 1.8 V ≤ EVDD0 ≤ 5.5 V | | 6/fMCK and 750 | | 6/fMCK and 750 | | 6/fMCK and 750 | | ns |
| | | 1.7 V ≤ EVDD0 ≤ 5.5 V | | 6/fMCK and 1500 | | 6/fMCK and 1500 | | 6/fMCK and 1500 | | ns |
| | | 1.6 V ≤ EVDD0 ≤ 5.5 V | | — | | 6/fMCK and 1500 | | 6/fMCK and 1500 | | ns |
| SCKp high-/low-level width | tkH2, tkL2 | 4.0 V ≤ EVDD0 ≤ 5.5 V | | tkCY2/2 - 7 | | tkCY2/2 - 7 | | tkCY2/2 - 7 | | ns |
| | | 2.7 V ≤ EVDD0 ≤ 5.5 V | | tkCY2/2 - 8 | | tkCY2/2 - 8 | | tkCY2/2 - 8 | | ns |
| | | 1.8 V ≤ EVDD0 ≤ 5.5 V | | tkCY2/2 - 18 | | tkCY2/2 - 18 | | tkCY2/2 - 18 | | ns |
| | | 1.7 V ≤ EVDD0 ≤ 5.5 V | | tkCY2/2 - 66 | | tkCY2/2 - 66 | | tkCY2/2 - 66 | | ns |
| | | 1.6 V ≤ EVDD0 ≤ 5.5 V | | — | | tkCY2/2 - 66 | | tkCY2/2 - 66 | | ns |
| Slp setup time (to SCKp↑) <small>Note 1</small> | tsIK2 | 2.7 V ≤ EVDD0 ≤ 5.5 V | | 1/fMCK + 20 | | 1/fMCK + 30 | | 1/fMCK + 30 | | ns |
| | | 1.8 V ≤ EVDD0 ≤ 5.5 V | | 1/fMCK + 30 | | 1/fMCK + 30 | | 1/fMCK + 30 | | ns |
| | | 1.7 V ≤ EVDD0 ≤ 5.5 V | | 1/fMCK + 40 | | 1/fMCK + 40 | | 1/fMCK + 40 | | ns |
| | | 1.6 V ≤ EVDD0 ≤ 5.5 V | | — | | 1/fMCK + 40 | | 1/fMCK + 40 | | ns |
| Slp hold time (from SCKp↑) <small>Note 2</small> | tkSI2 | 1.8 V ≤ EVDD0 ≤ 5.5 V | | 1/fMCK + 31 | | 1/fMCK + 31 | | 1/fMCK + 31 | | ns |
| | | 1.7 V ≤ EVDD0 ≤ 5.5 V | | 1/fMCK + 250 | | 1/fMCK + 250 | | 1/fMCK + 250 | | ns |
| | | 1.6 V ≤ EVDD0 ≤ 5.5 V | | — | | 1/fMCK + 250 | | 1/fMCK + 250 | | ns |
| Delay time from SCKp↓ to SOp output <small>Note 3</small> | tkSO2 | C = 30 pF <small>Note 4</small> | 2.7 V ≤ EVDD0 ≤ 5.5 V | | 2/fMCK + 44 | | 2/fMCK + 110 | | 2/fMCK + 110 | ns |
| | | | 2.4 V ≤ EVDD0 ≤ 5.5 V | | 2/fMCK + 75 | | 2/fMCK + 110 | | 2/fMCK + 110 | ns |
| | | | 1.8 V ≤ EVDD0 ≤ 5.5 V | | 2/fMCK + 100 | | 2/fMCK + 110 | | 2/fMCK + 110 | ns |
| | | | 1.7 V ≤ EVDD0 ≤ 5.5 V | | 2/fMCK + 220 | | 2/fMCK + 220 | | 2/fMCK + 220 | ns |
| | | | 1.6 V ≤ EVDD0 ≤ 5.5 V | | — | | 2/fMCK + 220 | | 2/fMCK + 220 | ns |

Note 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

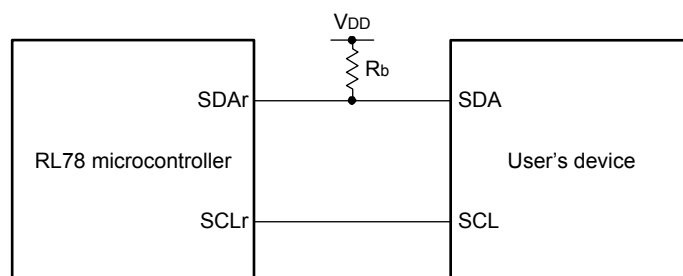
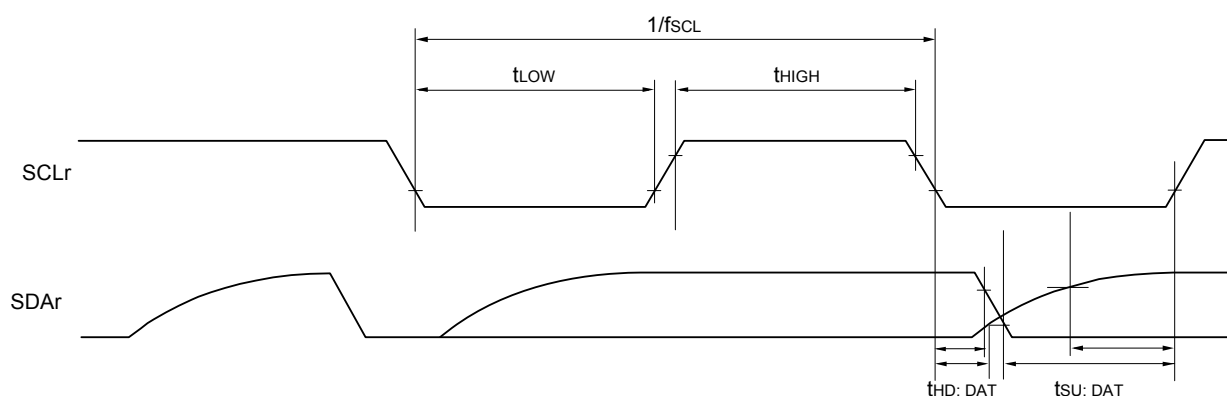
Note 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 4. C is the load capacitance of the SOp output lines.

Note 5. The maximum transfer rate when using the SNOOZE mode is 1 Mbps.

Caution Select the normal input buffer for the Slp pin and SCKp pin and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

Simplified I²C mode connection diagram (during communication at same potential)**Simplified I²C mode serial transfer timing (during communication at same potential)**

Remark 1. $R_b[\Omega]$: Communication line (SDAr) pull-up resistance, $C_b[F]$: Communication line (SDAr, SCLr) load capacitance

Remark 2. r: IIC number (r = 00, 01, 10, 11, 20, 21), g: PIM number (g = 0, 1, 3, 5, 7),
h: POM number (h = 0, 1, 3, 5, 7)

Remark 3. f_{MCK} : Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0, 1),
n: Channel number (n = 0 to 3), mn = 00 to 03, 10, 11)

(10) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I²C mode)**(TA = -40 to +85°C, 1.8 V ≤ EVDD0 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = 0 V)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | LS (low-speed main) mode | | LV (low-voltage main) mode | | Unit |
|---------------------------|--------|--|---------------------------|-------------|--------------------------|------------|----------------------------|------------|------|
| | | | MIN. | MAX. | MIN. | MAX. | MIN. | MAX. | |
| SCLr clock frequency | fSCL | 4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 50 pF, Rb = 2.7 kΩ | | 1000 Note 1 | | 300 Note 1 | | 300 Note 1 | kHz |
| | | 2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 50 pF, Rb = 2.7 kΩ | | 1000 Note 1 | | 300 Note 1 | | 300 Note 1 | kHz |
| | | 4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 100 pF, Rb = 2.8 kΩ | | 400 Note 1 | | 300 Note 1 | | 300 Note 1 | kHz |
| | | 2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 100 pF, Rb = 2.7 kΩ | | 400 Note 1 | | 300 Note 1 | | 300 Note 1 | kHz |
| | | 1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 100 pF, Rb = 5.5 kΩ | | 300 Note 1 | | 300 Note 1 | | 300 Note 1 | kHz |
| Hold time when SCLr = "L" | tLOW | 4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 50 pF, Rb = 2.7 kΩ | 475 | | 1550 | | 1550 | | ns |
| | | 2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 50 pF, Rb = 2.7 kΩ | 475 | | 1550 | | 1550 | | ns |
| | | 4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 100 pF, Rb = 2.8 kΩ | 1150 | | 1550 | | 1550 | | ns |
| | | 2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 100 pF, Rb = 2.7 kΩ | 1150 | | 1550 | | 1550 | | ns |
| | | 1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 100 pF, Rb = 5.5 kΩ | 1550 | | 1550 | | 1550 | | ns |
| Hold time when SCLr = "H" | tHIGH | 4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 50 pF, Rb = 2.7 kΩ | 245 | | 610 | | 610 | | ns |
| | | 2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 50 pF, Rb = 2.7 kΩ | 200 | | 610 | | 610 | | ns |
| | | 4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 100 pF, Rb = 2.8 kΩ | 675 | | 610 | | 610 | | ns |
| | | 2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 100 pF, Rb = 2.7 kΩ | 600 | | 610 | | 610 | | ns |
| | | 1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 100 pF, Rb = 5.5 kΩ | 610 | | 610 | | 610 | | ns |

(2) When reference voltage (+) = $AV_{REFP}/ANI0$ ($ADREFP1 = 0$, $ADREFP0 = 1$), reference voltage (-) = $AV_{REFM}/ANI1$ ($ADREFM = 1$), target pin: ANI16 to ANI24

(TA = -40 to +85°C, $1.6\text{ V} \leq EV_{DD0} \leq V_{DD} \leq 5.5\text{ V}$, $1.6\text{ V} \leq AV_{REFP} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = EV_{SS0} = 0\text{ V}$, Reference voltage (+) = AV_{REFP} , Reference voltage (-) = $AV_{REFM} = 0\text{ V}$)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------------------------|------------|--|--|--------|----------------------------------|------|
| Resolution | RES | | 8 | | 10 | bit |
| Overall error Note 1 | AINL | 10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ Notes 3, 4 | $1.8\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$ | 1.2 | ±5.0 | LSB |
| | | | $1.6\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$ Note 5 | 1.2 | ±8.5 | LSB |
| Conversion time | t_{CONV} | 10-bit resolution Target ANI pin: ANI16 to ANI24 | $3.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ | 2.125 | 39 | μs |
| | | | $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ | 3.1875 | 39 | μs |
| | | | $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ | 17 | 39 | μs |
| | | | $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ | 57 | 95 | μs |
| Zero-scale error Notes 1, 2 | E_{ZS} | 10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ Notes 3, 4 | $1.8\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$ | | ±0.35 | %FSR |
| | | | $1.6\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$ Note 5 | | ±0.60 | %FSR |
| Full-scale error Notes 1, 2 | E_{FS} | 10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ Notes 3, 4 | $1.8\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$ | | ±0.35 | %FSR |
| | | | $1.6\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$ Note 5 | | ±0.60 | %FSR |
| Integral linearity error Note 1 | ILE | 10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ Notes 3, 4 | $1.8\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$ | | ±3.5 | LSB |
| | | | $1.6\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$ Note 5 | | ±6.0 | LSB |
| Differential linearity error Note 1 | DLE | 10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ Notes 3, 4 | $1.8\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$ | | ±2.0 | LSB |
| | | | $1.6\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$ Note 5 | | ±2.5 | LSB |
| Analog input voltage | V_{AIN} | ANI16 to ANI24 | 0 | | AV_{REFP} and EV_{DD0} | V |

Note 1. Excludes quantization error ($\pm 1/2$ LSB).

Note 2. This value is indicated as a ratio (%FSR) to the full-scale value.

Note 3. When $EV_{DD0} \leq AV_{REFP} \leq V_{DD}$, the MAX. values are as follows.

Overall error: Add ± 1.0 LSB to the MAX. value when $AV_{REFP} = V_{DD}$.

Zero-scale error/Full-scale error: Add $\pm 0.05\%$ FSR to the MAX. value when $AV_{REFP} = V_{DD}$.

Integral linearity error/ Differential linearity error: Add ± 0.5 LSB to the MAX. value when $AV_{REFP} = V_{DD}$.

Note 4. When $AV_{REFP} < EV_{DD0} \leq V_{DD}$, the MAX. values are as follows.

Overall error: Add ± 4.0 LSB to the MAX. value when $AV_{REFP} = V_{DD}$.

Zero-scale error/Full-scale error: Add $\pm 0.20\%$ FSR to the MAX. value when $AV_{REFP} = V_{DD}$.

Integral linearity error/ Differential linearity error: Add ± 2.0 LSB to the MAX. value when $AV_{REFP} = V_{DD}$.

Note 5. When the conversion time is set to 57 μs (min.) and 95 μs (max.).

- (3) When reference voltage (+) = V_{DD} (ADREFP1 = 0, ADREFP0 = 0), reference voltage (-) = V_{SS} (ADREFM = 0), target pin: ANI0 to ANI17, ANI16 to ANI24, internal reference voltage, and temperature sensor output voltage

(TA = -40 to +85°C, 1.6 V ≤ EV_{DD0} ≤ V_{DD} ≤ 5.5 V, V_{SS} = EV_{SS0} = 0 V, Reference voltage (+) = V_{DD}, Reference voltage (-) = V_{SS})

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|--|-------------------|--|--|----------------------------|------|-------------------|------|
| Resolution | RES | | | 8 | | 10 | bit |
| Overall error Note 1 | AINL | 10-bit resolution Target pin: ANI0 to ANI17, ANI16 to ANI24 | 1.8 V ≤ V _{DD} ≤ 5.5 V | | 1.2 | ±7.0 | LSB |
| | | | 1.6 V ≤ V _{DD} ≤ 5.5 V Note 3 | | 1.2 | ±10.5 | LSB |
| Conversion time | t _{CONV} | 10-bit resolution Target pin: ANI0 to ANI17, ANI16 to ANI24 | 3.6 V ≤ V _{DD} ≤ 5.5 V | 2.125 | | 39 | μs |
| | | | 2.7 V ≤ V _{DD} ≤ 5.5 V | 3.1875 | | 39 | μs |
| | | | 1.8 V ≤ V _{DD} ≤ 5.5 V | 17 | | 39 | μs |
| | | | 1.6 V ≤ V _{DD} ≤ 5.5 V | 57 | | 95 | μs |
| | | 10-bit resolution Target pin: internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode) | 3.6 V ≤ V _{DD} ≤ 5.5 V | 2.375 | | 39 | μs |
| | | | 2.7 V ≤ V _{DD} ≤ 5.5 V | 3.5625 | | 39 | μs |
| | | | 2.4 V ≤ V _{DD} ≤ 5.5 V | 17 | | 39 | μs |
| | | | | | | | |
| Zero-scale error Notes 1, 2 | E _{zs} | 10-bit resolution | 1.8 V ≤ V _{DD} ≤ 5.5 V | | | ±0.60 | %FSR |
| | | | 1.6 V ≤ V _{DD} ≤ 5.5 V Note 3 | | | ±0.85 | %FSR |
| Full-scale error Notes 1, 2 | E _{fs} | 10-bit resolution | 1.8 V ≤ V _{DD} ≤ 5.5 V | | | ±0.60 | %FSR |
| | | | 1.6 V ≤ V _{DD} ≤ 5.5 V Note 3 | | | ±0.85 | %FSR |
| Integral linearity error Note 1 | ILE | 10-bit resolution | 1.8 V ≤ V _{DD} ≤ 5.5 V | | | ±4.0 | LSB |
| | | | 1.6 V ≤ V _{DD} ≤ 5.5 V Note 3 | | | ±6.5 | LSB |
| Differential linearity error Note 1 | DLE | 10-bit resolution | 1.8 V ≤ V _{DD} ≤ 5.5 V | | | ±2.0 | LSB |
| | | | 1.6 V ≤ V _{DD} ≤ 5.5 V Note 3 | | | ±2.5 | LSB |
| Analog input voltage | V _{AIN} | ANI0 to ANI7 | | 0 | | V _{DD} | V |
| | | ANI16 to ANI24 | | 0 | | EV _{DD0} | V |
| | | Internal reference voltage (2.4 V ≤ V _{DD} ≤ 5.5 V, HS (high-speed main) mode) | | V _{BGR} Note 4 | | | V |
| | | Temperature sensor output voltage (2.4 V ≤ V _{DD} ≤ 5.5 V, HS (high-speed main) mode) | | V _{TMPS25} Note 4 | | | V |

Note 1. Excludes quantization error (±1/2 LSB).

Note 2. This value is indicated as a ratio (% FSR) to the full-scale value.

Note 3. When the conversion time is set to 57 μs (min.) and 95 μs (max.).

Note 4. Refer to 2.6.2 Temperature sensor characteristics/internal reference voltage characteristic.

- (4) When reference voltage (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), reference voltage (-) = AVREFM/ANI1 (ADREFM = 1), target pin: ANI0, ANI2 to ANI7, ANI16 to ANI24

(TA = -40 to +85°C, 2.4 V ≤ VDD ≤ 5.5 V, 1.6 V ≤ EVDD0 ≤ VDD, VSS = EVSS0 = 0 V, Reference voltage (+) = VBGR ^{Note 3}, Reference voltage (-) = AVREFM = 0 V ^{Note 4}, HS (high-speed main) mode)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|--|--------|------------------|---------------------|------|------|------------------------|-------|
| Resolution | RES | | | 8 | | | bit |
| Conversion time | tCONV | 8-bit resolution | 2.4 V ≤ VDD ≤ 5.5 V | 17 | | 39 | μs |
| Zero-scale error ^{Notes 1, 2} | Ezs | 8-bit resolution | 2.4 V ≤ VDD ≤ 5.5 V | | | ±0.60 | % FSR |
| Integral linearity error ^{Note 1} | ILE | 8-bit resolution | 2.4 V ≤ VDD ≤ 5.5 V | | | ±2.0 | LSB |
| Differential linearity error ^{Note 1} | DLE | 8-bit resolution | 2.4 V ≤ VDD ≤ 5.5 V | | | ±1.0 | LSB |
| Analog input voltage | VAIN | | | 0 | | VBGR ^{Note 3} | V |

Note 1. Excludes quantization error (±1/2 LSB).

Note 2. This value is indicated as a ratio (% FSR) to the full-scale value.

Note 3. Refer to **2.6.2 Temperature sensor characteristics/internal reference voltage characteristic**.

Note 4. When reference voltage (-) = VSS, the MAX. values are as follows.

Zero-scale error: Add ±0.35%FSR to the MAX. value when reference voltage (-) = AVREFM.

Integral linearity error: Add ±0.5 LSB to the MAX. value when reference voltage (-) = AVREFM.

Differential linearity error: Add ±0.2 LSB to the MAX. value when reference voltage (-) = AVREFM.

3.3.2 Supply current characteristics

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = 0 V)

(1/2)

| Parameter | Symbol | Conditions | | | | | MIN. | TYP. | MAX. | Unit |
|--------------------------|--------|----------------|----------------------------------|---|------------------|----------------------|------|------|------|------|
| Supply current Note 1 | IDD1 | Operating mode | HS (high-speed main) mode Note 5 | fHOCO = 64 MHz, fIH = 32 MHz Note 3 | Basic operation | VDD = 5.0 V | | 2.4 | | mA |
| | | | | | | VDD = 3.0 V | | 2.4 | | |
| | | | | fHOCO = 32 MHz, fIH = 32 MHz Note 3 | Basic operation | VDD = 5.0 V | | 2.1 | | |
| | | | | | | VDD = 3.0 V | | 2.1 | | |
| | | | HS (high-speed main) mode Note 5 | fHOCO = 64 MHz, fIH = 32 MHz Note 3 | Normal operation | VDD = 5.0 V | | 5.2 | 9.3 | mA |
| | | | | | | VDD = 3.0 V | | 5.2 | 9.3 | |
| | | | | fHOCO = 32 MHz, fIH = 32 MHz Note 3 | Normal operation | VDD = 5.0 V | | 4.8 | 8.7 | |
| | | | | | | VDD = 3.0 V | | 4.8 | 8.7 | |
| | | | | fHOCO = 48 MHz, fIH = 24 MHz Note 3 | Normal operation | VDD = 5.0 V | | 4.1 | 7.3 | |
| | | | | | | VDD = 3.0 V | | 4.1 | 7.3 | |
| | | | | fHOCO = 24 MHz, fIH = 24 MHz Note 3 | Normal operation | VDD = 5.0 V | | 3.8 | 6.7 | |
| | | | | | | VDD = 3.0 V | | 3.8 | 6.7 | |
| | | | | fHOCO = 16 MHz, fIH = 16 MHz Note 3 | Normal operation | VDD = 5.0 V | | 2.8 | 4.9 | |
| | | | | | | VDD = 3.0 V | | 2.8 | 4.9 | |
| | | | HS (high-speed main) mode Note 5 | fMX = 20 MHz Note 2, VDD = 5.0 V | Normal operation | Square wave input | | 3.3 | 5.7 | mA |
| | | | | | | Resonator connection | | 3.5 | 5.8 | |
| | | | | fMX = 20 MHz Note 2, VDD = 3.0 V | Normal operation | Square wave input | | 3.3 | 5.7 | |
| | | | | | | Resonator connection | | 3.5 | 5.8 | |
| | | | | fMX = 10 MHz Note 2, VDD = 5.0 V | Normal operation | Square wave input | | 2.0 | 3.4 | |
| | | | | | | Resonator connection | | 2.1 | 3.5 | |
| | | | | fMX = 10 MHz Note 2, VDD = 3.0 V | Normal operation | Square wave input | | 2.0 | 3.4 | |
| | | | | | | Resonator connection | | 2.1 | 3.5 | |
| | | | Subsystem clock operation | fSUB = 32.768 kHz Note 4 TA = -40°C | Normal operation | Square wave input | | 4.7 | 6.1 | μA |
| | | | | | | Resonator connection | | 4.7 | 6.1 | |
| | | | | fSUB = 32.768 kHz Note 4 TA = +25°C | Normal operation | Square wave input | | 4.7 | 6.1 | |
| | | | | | | Resonator connection | | 4.7 | 6.1 | |
| | | | | fSUB = 32.768 kHz Note 4 TA = +50°C | Normal operation | Square wave input | | 4.8 | 6.7 | |
| | | | | | | Resonator connection | | 4.8 | 6.7 | |
| | | | | fSUB = 32.768 kHz Note 4 TA = +70°C | Normal operation | Square wave input | | 4.8 | 7.5 | |
| | | | | | | Resonator connection | | 4.8 | 7.5 | |
| | | | | fSUB = 32.768 kHz Note 4 TA = +85°C | Normal operation | Square wave input | | 5.4 | 8.9 | |
| | | | | | | Resonator connection | | 5.4 | 8.9 | |
| | | | | fSUB = 32.768 kHz Note 4 TA = +105°C | Normal operation | Square wave input | | 7.2 | 21.0 | |
| | | | | | | Resonator connection | | 7.3 | 21.1 | |

(Notes and Remarks are listed on the next page.)

- Note 1.** Total current flowing into VDD and EVDD0, including the input leakage current flowing when the level of the input pin is fixed to VDD, EVDD0 or VSS, EVSS0. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** During HALT instruction execution by flash memory.
- Note 3.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 4.** When high-speed system clock and subsystem clock are stopped.
- Note 5.** When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
- Note 6.** Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
- Note 7.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
 HS (high-speed main) mode: $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$
- Note 8.** Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.
- Remark 1.** fMX: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2.** fHOCO: High-speed on-chip oscillator clock frequency (64 MHz max.)
- Remark 3.** fIH: High-speed on-chip oscillator clock frequency (32 MHz max.)
- Remark 4.** fSUB: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 5.** Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is TA = 25°C

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = 0 V)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|--|--------------------|--|---|------|------|------|------|
| Low-speed on-chip oscillator operating current | IFIL Note 1 | | | | 0.2 | | μA |
| RTC operating current | IRTC Notes 1, 2, 3 | | | | 0.02 | | μA |
| 12-bit interval timer operating current | IIT Notes 1, 2, 4 | | | | 0.02 | | μA |
| Watchdog timer operating current | IWDT Notes 1, 2, 5 | fIL = 15 kHz | | | 0.22 | | μA |
| A/D converter operating current | IADC Notes 1, 6 | When conversion at maximum speed | Normal mode, AVREFP = VDD = 5.0 V | | 1.3 | 1.7 | mA |
| | | | Low voltage mode, AVREFP = VDD = 3.0 V | | 0.5 | 0.7 | mA |
| A/D converter reference voltage current | IADREF Note 1 | | | | 75 | | μA |
| Temperature sensor operating current | ITMPS Note 1 | | | | 75 | | μA |
| D/A converter operating current | IDAC Notes 1, 11 | Per D/A converter channel | | | | 1.5 | mA |
| PGA operating current | | Operation | | | 480 | 700 | μA |
| Comparator operating current | ICMP Notes 1, 12 | Operation (per comparator channel, constant current for comparator included) | When the internal reference voltage is not in use | | 50 | 100 | μA |
| | | | When the internal reference voltage is in use | | 60 | 110 | μA |
| LVD operating current | ILVD Notes 1, 7 | | | | 0.08 | | μA |
| Self-programming operating current | IFSP Notes 1, 9 | | | | 2.50 | 12.2 | mA |
| BGO operating current | IBGO Notes 1, 8 | | | | 2.50 | 12.2 | mA |
| SNOOZE operating current | ISNOZ Note 1 | ADC operation | The mode is performed Note 10 | | 0.50 | 1.10 | mA |
| | | | The A/D conversion operations are performed, Low voltage mode, AVREFP = VDD = 3.0 V | | 1.20 | 2.04 | |
| | | CSI/UART operation | | | 0.70 | 1.54 | |
| | | DTC operation | | | 3.10 | | |

Note 1. Current flowing to VDD.**Note 2.** When high speed on-chip oscillator and high-speed system clock are stopped.**Note 3.** Current flowing only to the real-time clock (RTC) (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and IRTC, when the real-time clock operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, IFIL should be added. IDD2 subsystem clock operation includes the operational current of the real-time clock.**Note 4.** Current flowing only to the 12-bit interval timer (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and IIT, when the 12-bit interval timer operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, IFIL should be added.**Note 5.** Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The supply current of the RL78 microcontrollers is the sum of IDD1, IDD2 or IDD3 and IWDT when the watchdog timer is in operation.**Note 6.** Current flowing only to the A/D converter. The supply current of the RL78 microcontrollers is the sum of IDD1 or IDD2 and IADC when the A/D converter operates in an operation mode or the HALT mode.**Note 7.** Current flowing only to the LVD circuit. The supply current of the RL78 microcontrollers is the sum of IDD1, IDD2 or IDD3 and ILVD when the LVD circuit is in operation.**Note 8.** Current flowing during programming of the data flash.**Note 9.** Current flowing during self-programming.**Note 10.** For shift time to the SNOOZE mode, see **26.3.3 SNOOZE mode** in the RL78/G1F User's Manual.

- Note 11.** Current flowing only to the D/A converter. The supply current of the RL78 microcontrollers is the sum of IDD1 or IDD2 and IDAC when the D/A converter operates in an operation mode or the HALT mode.
- Note 12.** Current flowing only to the comparator circuit. The supply current of the RL78 microcontrollers is the sum of IDD1, IDD2, or IDD3 and ICMP when the comparator circuit is in operation.
- Remark 1.** f_{IL}: Low-speed on-chip oscillator clock frequency
- Remark 2.** f_{SUB}: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 3.** f_{CLK}: CPU/peripheral hardware clock frequency
- Remark 4.** Temperature condition of the TYP. value is TA = 25°C

(5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)**(TA = -40 to +105°C, 2.4 V ≤ EVDD0 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = 0 V)****(1/2)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|---------------|--------|------------|--|-----------------------|------|
| | | | MIN. | MAX. | |
| Transfer rate | | reception | 4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V | fMCK/12 Note 1 | bps |
| | | | | 2.6 | Mbps |
| | | | Theoretical value of the maximum transfer rate fMCK = fCLK Note 3 | | |
| | | | 2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V | fMCK/12 Note 1 | bps |
| | | | | 2.6 | Mbps |
| | | | Theoretical value of the maximum transfer rate fMCK = fCLK Note 3 | | |
| | | | 2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V | fMCK/12 Notes 1, 2 | bps |
| | | | | 1.3 | Mbps |
| | | | Theoretical value of the maximum transfer rate fMCK = fCLK Note 3 | | |

Note 1. Transfer rate in the SNOOZE mode is 4800 bps only.

However, the SNOOZE mode cannot be used when FRQSEL4 = 1.

Note 2. The following conditions are required for low voltage interface when EVDD0 < VDD.

2.4 V ≤ EVDD0 < 2.7 V: MAX. 2.6 Mbps

1.8 V ≤ EVDD0 < 2.4 V: MAX. 1.3 Mbps

Note 3. The maximum operating frequencies of the CPU/peripheral hardware clock (fCLK) are:

HS (high-speed main) mode: 32 MHz (2.7 V ≤ VDD ≤ 5.5 V)

16 MHz (2.4 V ≤ VDD ≤ 5.5 V)

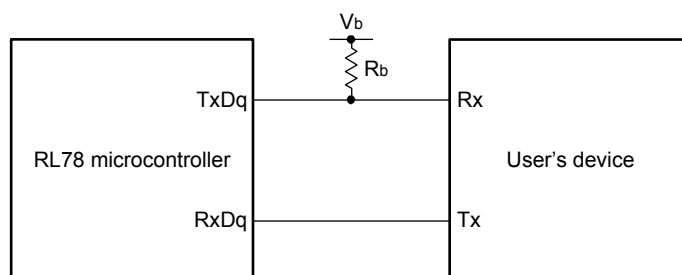
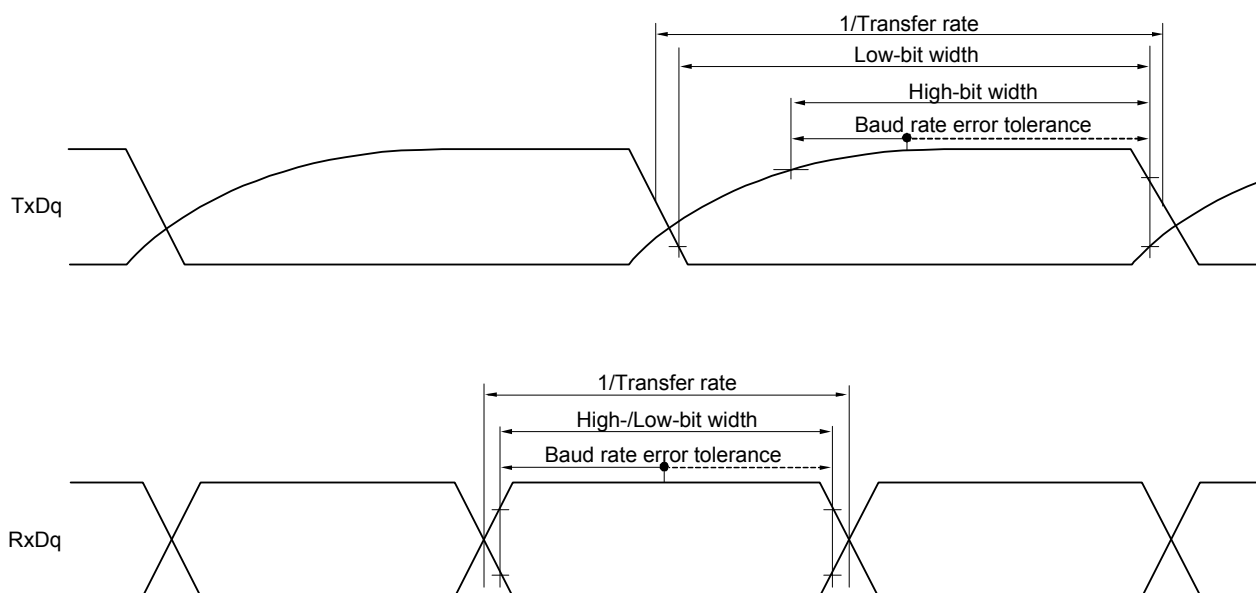
Caution Select the TTL input buffer for the RxDq pin and the N-ch open drain output (VDD tolerance (for the 48-, 32-, 24-pin products)/EVDD tolerance (for the 64-, 36-pin products)) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

Remark 1. Vb [V]: Communication line voltage**Remark 2.** q: UART number (q = 0 to 2), g: PIM and POM number (g = 0, 1, 5, 7)**Remark 3.** fMCK: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,

n: Channel number (mn = 00 to 03, 10, 11)

Remark 4. UART2 cannot communicate at different potential when bit 1 (PIOR01) of peripheral I/O redirection register 0 (PIOR0) is 1.

UART mode connection diagram (during communication at different potential)**UART mode bit width (during communication at different potential) (reference)**

Remark 1. $R_b[\Omega]$: Communication line (TxDq) pull-up resistance,

$C_b[\text{F}]$: Communication line (TxDq) load capacitance, $V_b[\text{V}]$: Communication line voltage

Remark 2. q: UART number (q = 0 to 2), g: PIM and POM number (g = 0, 1, 5, 7)

Remark 3. f_{MCK} : Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).

m: Unit number, n: Channel number (mn = 00 to 03, 10, 11))

Remark 4. UART2 cannot communicate at different potential when bit 1 (PIOR01) of peripheral I/O redirection register 0 (PIOR0) is 1.

(7) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (slave mode, SCKp... external clock input)**(TA = -40 to +105°C, 2.4 V ≤ EVDD0 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = 0 V)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|--|------------|---|---------------------------|---------------|------|
| | | | MIN. | MAX. | |
| SCKp cycle time ^{Note 1} | tkCY2 | 4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V | 24 MHz < fMCK | 28/fMCK | ns |
| | | | 20 MHz < fMCK ≤ 24 MHz | 24/fMCK | ns |
| | | | 8 MHz < fMCK ≤ 20 MHz | 20/fMCK | ns |
| | | | 4 MHz < fMCK ≤ 8 MHz | 16/fMCK | ns |
| | | | fMCK ≤ 4 MHz | 12/fMCK | ns |
| | | 2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V | 24 MHz < fMCK | 40/fMCK | ns |
| | | | 20 MHz < fMCK ≤ 24 MHz | 32/fMCK | ns |
| | | | 16 MHz < fMCK ≤ 20 MHz | 28/fMCK | ns |
| | | | 8 MHz < fMCK ≤ 16 MHz | 24/fMCK | ns |
| | | | 4 MHz < fMCK ≤ 8 MHz | 16/fMCK | ns |
| | | | fMCK ≤ 4 MHz | 12/fMCK | ns |
| | | 2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V | 24 MHz < fMCK | 96/fMCK | ns |
| | | | 20 MHz < fMCK ≤ 24 MHz | 72/fMCK | ns |
| | | | 16 MHz < fMCK ≤ 20 MHz | 64/fMCK | ns |
| | | | 8 MHz < fMCK ≤ 16 MHz | 52/fMCK | ns |
| | | | 4 MHz < fMCK ≤ 8 MHz | 32/fMCK | ns |
| | | | fMCK ≤ 4 MHz | 20/fMCK | ns |
| SCKp high-/low-level width | tkH2, tkL2 | 4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V | tkCY2/2 - 24 | | ns |
| | | 2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V | tkCY2/2 - 36 | | ns |
| | | 2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V | tkCY2/2 - 100 | | ns |
| Slp setup time (to SCKp↑) ^{Note 2} | tsIK2 | 2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V | 1/fMCK + 40 | | ns |
| | | 2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V | 1/fMCK + 60 | | ns |
| Slp hold time (from SCKp↑) ^{Note 3} | tsI2 | | 1/fMCK + 62 | | ns |
| Delay time from SCKp↓ to SOp output ^{Note 4} | tkSO2 | 4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ | | 2/fMCK + 240 | ns |
| | | 2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ | | 2/fMCK + 428 | ns |
| | | 2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V, Cb = 30 pF, Rv = 5.5 kΩ | | 2/fMCK + 1146 | ns |

(Notes and Remarks are listed on the next page.)

3.6 Analog Characteristics

3.6.1 A/D converter characteristics

Classification of A/D converter characteristics

| Reference Voltage | Reference voltage (+) = AVREFP Reference voltage (-) = AVREFM | Reference voltage (+) = VDD Reference voltage (-) = VSS | Reference voltage (+) = VBGR Reference voltage (-) = AVREFM |
|---|--|--|--|
| Input channel | | | |
| ANI0 to ANI7 | Refer to 3.6.1 (1). | Refer to 3.6.1 (3). | Refer to 3.6.1 (4). |
| ANI16 to ANI24 | Refer to 3.6.1 (2). | | |
| Internal reference voltage Temperature sensor output voltage | Refer to 3.6.1 (1). | | — |

(1) When reference voltage (+) = AVREFP/ANI0 (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) = AVREFM/ANI1 (ADREFM = 1), target pin: ANI2 to ANI7, internal reference voltage, and temperature sensor output voltage

(TA = -40 to +105°C, 2.4 V ≤ AVREFP ≤ VDD ≤ 5.5 V, VSS = 0 V, Reference voltage (+) = AVREFP,
Reference voltage (-) = AVREFM = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------------------------|--------|---|------------------------|--------|--------|------|
| Resolution | RES | | 8 | | 10 | bit |
| Overall error Note 1 | AINL | 10-bit resolution AVREFP = VDD Note 3 | 2.4 V ≤ AVREFP ≤ 5.5 V | 1.2 | ±3.5 | LSB |
| Conversion time | tCONV | 10-bit resolution Target pin: ANI2 to ANI14 | 3.6 V ≤ VDD ≤ 5.5 V | 2.125 | 39 | μs |
| | | | 2.7 V ≤ VDD ≤ 5.5 V | 3.1875 | 39 | μs |
| | | | 2.4 V ≤ VDD ≤ 5.5 V | 17 | 39 | μs |
| | | 10-bit resolution Target pin: Internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode) | 3.6 V ≤ VDD ≤ 5.5 V | 2.375 | 39 | μs |
| | | | 2.7 V ≤ VDD ≤ 5.5 V | 3.5625 | 39 | μs |
| | | | 2.4 V ≤ VDD ≤ 5.5 V | 17 | 39 | μs |
| Zero-scale error Notes 1, 2 | EZS | 10-bit resolution AVREFP = VDD Note 3 | 2.4 V ≤ AVREFP ≤ 5.5 V | | ±0.25 | %FSR |
| Full-scale error Notes 1, 2 | EFS | 10-bit resolution AVREFP = VDD Note 3 | 2.4 V ≤ AVREFP ≤ 5.5 V | | ±0.25 | %FSR |
| Integral linearity error Note 1 | ILE | 10-bit resolution AVREFP = VDD Note 3 | 2.4 V ≤ AVREFP ≤ 5.5 V | | ±2.5 | LSB |
| Differential linearity error Note 1 | DLE | 10-bit resolution AVREFP = VDD Note 3 | 2.4 V ≤ AVREFP ≤ 5.5 V | | ±1.5 | LSB |
| Analog input voltage | VAIN | ANI2 to ANI7 | 0 | | AVREFP | V |
| | | Internal reference voltage output (2.4 V ≤ VDD ≤ 5.5 V, HS (high-speed main) mode) | VBGR Note 4 | | | V |
| | | Temperature sensor output voltage (2.4 V ≤ VDD ≤ 5.5 V, HS (high-speed main) mode) | VTMPS25 Note 4 | | | V |

Note 1. Excludes quantization error (±1/2 LSB).

Note 2. This value is indicated as a ratio (%FSR) to the full-scale value.

Note 3. When AVREFP < VDD, the MAX. values are as follows.

Overall error: Add ±1.0 LSB to the MAX. value when AVREFP = VDD.

Zero-scale error/Full-scale error: Add ±0.05%FSR to the MAX. value when AVREFP = VDD.

Integral linearity error/ Differential linearity error: Add ±0.5 LSB to the MAX. value when AVREFP = VDD.

Note 4. Refer to 3.6.2 Temperature sensor characteristics/internal reference voltage characteristic.

- (3) When reference voltage (+) = V_{DD} (ADREFP1 = 0, ADREFP0 = 0), reference voltage (-) = V_{SS} (ADREFM = 0), target pin: ANI0 to ANI7, ANI16 to ANI24, internal reference voltage, and temperature sensor output voltage

(TA = -40 to +105°C, 2.4 V ≤ EV_{DD0} ≤ V_{DD} ≤ 5.5 V, V_{SS} = EV_{SS0} = 0 V, Reference voltage (+) = V_{DD}, Reference voltage (-) = V_{SS})

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|--|-------------------|--|---------------------------------|----------------------------|------|-------------------|------|
| Resolution | RES | | | 8 | | 10 | bit |
| Overall error Note 1 | AINL | 10-bit resolution | 2.4 V ≤ V _{DD} ≤ 5.5 V | | 1.2 | ±7.0 | LSB |
| Conversion time | t _{CONV} | 10-bit resolution Target pin: ANI0 to ANI14, ANI16 to ANI20 | 3.6 V ≤ V _{DD} ≤ 5.5 V | 2.125 | | 39 | μs |
| | | | 2.7 V ≤ V _{DD} ≤ 5.5 V | 3.1875 | | 39 | μs |
| | | | 2.4 V ≤ V _{DD} ≤ 5.5 V | 17 | | 39 | μs |
| | | 10-bit resolution Target pin: internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode) | 3.6 V ≤ V _{DD} ≤ 5.5 V | 2.375 | | 39 | μs |
| | | | 2.7 V ≤ V _{DD} ≤ 5.5 V | 3.5625 | | 39 | μs |
| | | | 2.4 V ≤ V _{DD} ≤ 5.5 V | 17 | | 39 | μs |
| Zero-scale error Notes 1, 2 | E _{ZS} | 10-bit resolution | 2.4 V ≤ V _{DD} ≤ 5.5 V | | | ±0.60 | %FSR |
| Full-scale error Notes 1, 2 | E _{FS} | 10-bit resolution | 2.4 V ≤ V _{DD} ≤ 5.5 V | | | ±0.60 | %FSR |
| Integral linearity error Note 1 | ILE | 10-bit resolution | 2.4 V ≤ V _{DD} ≤ 5.5 V | | | ±4.0 | LSB |
| Differential linearity error Note 1 | DLE | 10-bit resolution | 2.4 V ≤ V _{DD} ≤ 5.5 V | | | ±2.0 | LSB |
| Analog input voltage | V _{AIN} | ANI0 to ANI7 | | 0 | | V _{DD} | V |
| | | ANI16 to ANI24 | | 0 | | EV _{DD0} | V |
| | | Internal reference voltage (2.4 V ≤ V _{DD} ≤ 5.5 V, HS (high-speed main) mode) | | V _{BGR} Note 3 | | | V |
| | | Temperature sensor output voltage (2.4 V ≤ V _{DD} ≤ 5.5 V, HS (high-speed main) mode) | | V _{TMPS25} Note 3 | | | V |

Note 1. Excludes quantization error (±1/2 LSB).

Note 2. This value is indicated as a ratio (% FSR) to the full-scale value.

Note 3. Refer to 3.6.2 Temperature sensor characteristics/internal reference voltage characteristic.

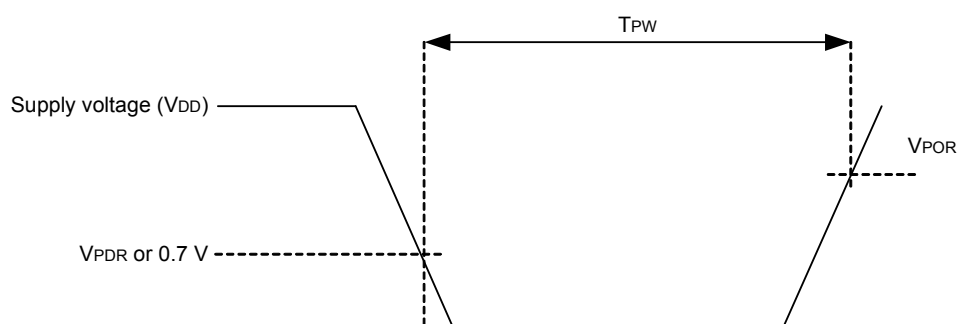
3.6.6 POR circuit characteristics

(TA = -40 to +105°C, VSS = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---------------------------------------|--------|--|------|------|------|------|
| Power on/down reset threshold | VPOR | Voltage threshold on VDD rising | 1.45 | 1.51 | 1.55 | V |
| | VPDR | Voltage threshold on VDD falling ^{Note 1} | 1.44 | 1.50 | 1.54 | V |
| Minimum pulse width ^{Note 2} | TPW | | 300 | | | μs |

Note 1. However, when the operating voltage falls while the LVD is off, enter STOP mode, or enable the reset status using the external reset pin before the voltage falls below the operating voltage range shown in **3.4 AC Characteristics**.

Note 2. Minimum time required for a POR reset when VDD exceeds below VPDR. This is also the minimum time required for a POR reset from when VDD exceeds below 0.7 V to when VDD exceeds VPOR while STOP mode is entered or the main system clock is stopped through setting bit 0 (HIOSSTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).



4.4 48-pin products

R5F11BGCAFB, R5F11BGEAFB, R5F11BGCGFB, R5F11BGEGFB

